NSN 5961-01-293-2058 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
1.587 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Overall Width Across Flats:
Between 0.552 inches and 0.562 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 repetitive peak off-state voltage and 600.0 repetitive peak off-state voltage and 200.0 repetitive peak reverse voltage and 600.0
repetitive peak reverse voltage
Current Rating Per Characteristic:
6.00 amperes forward current, total rms horsepower metric and 50.00 milliamperes forward current, total rms absolute
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
<del>-</del>
Demilitarization:
No
Fiig:
A110a0